

# Specification of MEMS Microphone

(GGS3177 & Halogen-free)

**Customer Name:** 

**Customer Model:** 

GoerTek Model: SD18OB261-104

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Confidential Degree : Confidential

# Restricted

# 1 Security Warning

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# 2 Publication History

Version	Description	Date	Author	Approved
1.0	New Design	2021.01.06	Aaron	Roy
2.0	Updata Microphone Interface Specifications	2021.05.15	Aaron	Roy

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#### 1 Introduction:

MEMS MIC which is able to endure reflow temperature up to 260  $^{\circ}$ C for 50 seconds can be used in SMT process. It is widely used in telecommunication and electronics device such as mobile phone, MP3, PDAs etc.

# 2 Test Condition (L=50 cm)

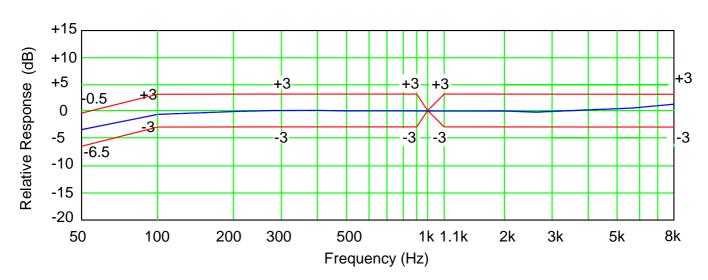
StandardConditions (As IEC 60268-4)	Temperature	Humidity	Air pressure
Environment Conditions	+15°C∼+35°C	25%RH~75%RH	86kPa $\sim$ 106kPa
Basic Test Conditions	+20℃±2℃	60%RH~70%RH	86kPa∼106kPa

#### 3 Acoustical and Electrical Characteristics

#### 3.1 Standard Performance Mode (Test Condition: V DD=1.8V, fCLK=2.4MHz)

Item	Symbol	Test Conditions	Min	Тур	Max	Unit
Sensitivity	S	f=1kHz, Pin=1Pa	-27	-26	-25	dBFS (Note 1)
Current Consumption (Note 2)	Ι	f <sub>clk</sub> =2.4MHz	-	750	900	μΑ
S/N Ratio	SNR	f=1kHz, P <sub>in</sub> =1Pa A-Weighted Curve	-	65	-	dB
Distortion	THD	94dB SPL@ 1kHz	-	0.1	1	%
Acoustic Overload Point	AOP	10% THD @1 kHz	-	120	-	dB SPL
Power Supply Rejection	PSR	100mVpp squarewave @217Hz, A-welghted	-	-80	-	dBFS
Power Supply Rejection Ratio	PSRR	200mVpp Sine wave @1KHz	-	60	-	dBFS

#### 3.2 Frequency Response Curve and Limits





# 3.3 Low Power Mode (Test Condition: V<sub>DD</sub>=1.8V, f<sub>CLK</sub>=768kHz)

Item	Symbol	Test Conditions	Min	Тур	Max	Unit
Sensitivity	S	f=1kHz, Pin=1Pa	-27	-26	-25	dBFS (Note 1)
Current Consumption (Note 2)	Ι	f <sub>cik</sub> =768kHz	-	300	350	μA
S/N Ratio	SNR	f=1kHz, P <sub>in</sub> =1Pa A-Weighted Curve	-	64	-	dB
Distortion	THD	94dB SPL@ 1kHz	-	0.2	1	%
Acoustic Overload Point	AOP	10% THD @1 kHz	-	120	-	dB SPL
Power Supply Rejection	PSR	100mVpp squarewave @217Hz, A-welghted	-	-86	-	dBFS
Power Supply Rejection Ratio	PSRR	200mVpp Sine wave @1KHz	-	60	-	dBFS

## 3.4 General Microphone Specifications

Test Condition: V<sub>DD</sub>=1.8V,f<sub>CLK</sub>=2.4MHz, select pin grounded,no load.

	ltem	Symbol	Test Conditions	Min	Тур	Max	Unit
Sup	ply Voltage	$V_{DD}$		1.60	-	3.6	V
Clock	Standby Mode			0		50	kHz
Frequency Range	Lower Power Mode			150	768	900	kHz
J. J.	Normal Mode			1.0	-	4.8	MHz
Slee	p Current	l <sub>sleep</sub>	Fclk=0Hz, Vdd=1.8V	-	3		μΑ
Di	rectivity			Omnidirectional			
F	Polarity		Increasing Sound	Increasing density of 1's		l's	
Dat	a Format			PDM			
Short Ci	rcuit Current	I <sub>SC</sub>	Ground Data Pin			20	mA
Out	put Load	C <sub>load</sub>				140	pF
Fall A	sleep Time	Tlsp	Fclk<50KHz		5		us
Wake	e-up Time	Twk	±0.5dB sensitivity accuracy			20	ms
Powe	r Up Time	Tpu	±0.5dB sensitivity accuracy			20	ms
Mode C	Change Time	Tmc	±0.5dB sensitivity accuracy			20	ms



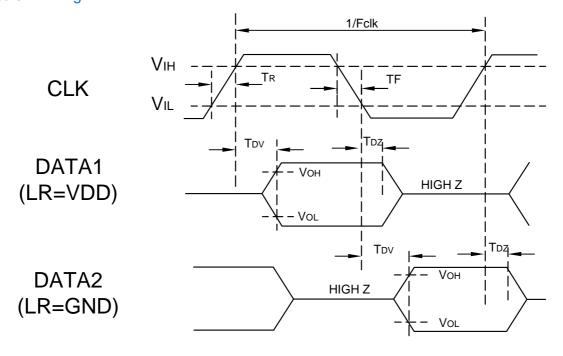
#### 3.5 Microphone Interface Specifications

	Item	Symbol	Test Conditions	Min	Тур	Max	Unit
Sup	ply Voltage	$V_{DD}$		1.60	-	3.6	V
Clock	Standby Mode			0		50	kHz
Frequency Range	Lower Power Mode			150	768	900	kHz
l tonigo	Normal Mode			1.0	-	4.8	MHz
Slee	p Current	l <sub>sleep</sub>	Fclk=0Hz, Vdd=1.8V	-	3		μΑ
Di	rectivity			Omnidirectional			
F	Polarity		Increasing Sound	Increasing density of 1's		's	
Dat	a Format			PDM			
Short C	ircuit Current	I <sub>SC</sub>	Ground Data Pin			20	mA
Out	put Load	C <sub>load</sub>				140	pF
Fall A	sleep Time	Tlsp	Fclk<50KHz		5		us
Wake	e-up Time	Twk	±0.5dB sensitivity accuracy			20	ms
Powe	r Up Time	Tpu	±0.5dB sensitivity accuracy			20	ms
Mode C	Change Time	Tmc	±0.5dB sensitivity accuracy			20	ms

Note 1. dBFS = 20xlog (A/B) where A is the level of the signal, B is the level that corrsponds to Full-scale level.

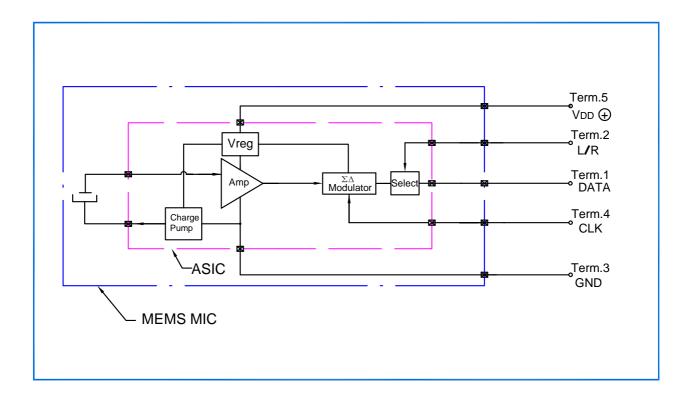
Note 2. The current consumption depends on the applied Clock Frequency and the load on the DATA output.

Note 3. Timing

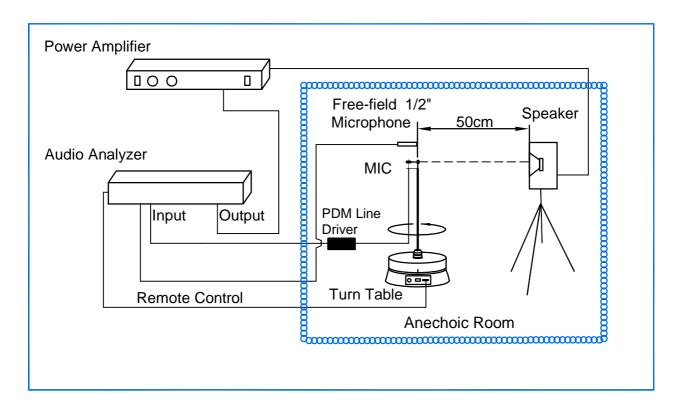




### **4 Measurement Circuit**



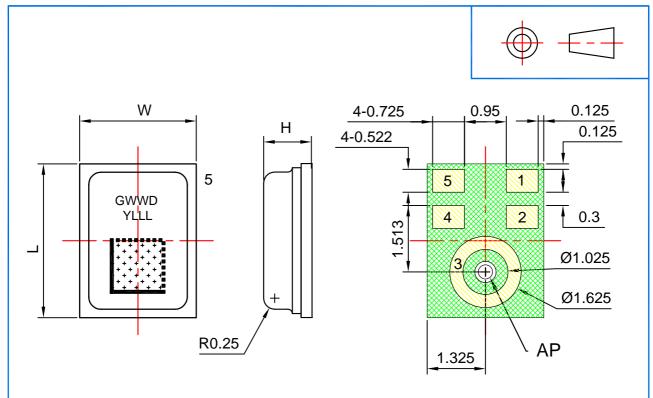
# 5 Test Setup Drawing





#### **6 Mechanical Characteristics**

#### 6.1 Appearance Drawing (Unit: mm)



Side View

**Bottom View** 

Pin#	Function	
1	Data	
2	L/R	
3	GND	
4	CLK	
5	VDD	

ITEM	DIMENSION	TOLERANCE	UNITS
Length(L)	3.50	±0.10	mm
Width(W)	2.65	±0.10	mm
Height(H)	0.98	±0.10	mm
ACOUSTIC PORT(AP)	Ø0.325	±0.05	mm

Note: 1. Tolerance ±0.10mm unless otherwise specified.

2. Identification Number Convention: Job Identification Number.

Identification Number

G	W	W	D
Υ	L	Ш	L

G: GoerTek

Y:Year



LLL: Lot Number





6.2 Weight

The weight of the MIC is Less than 0.05g.



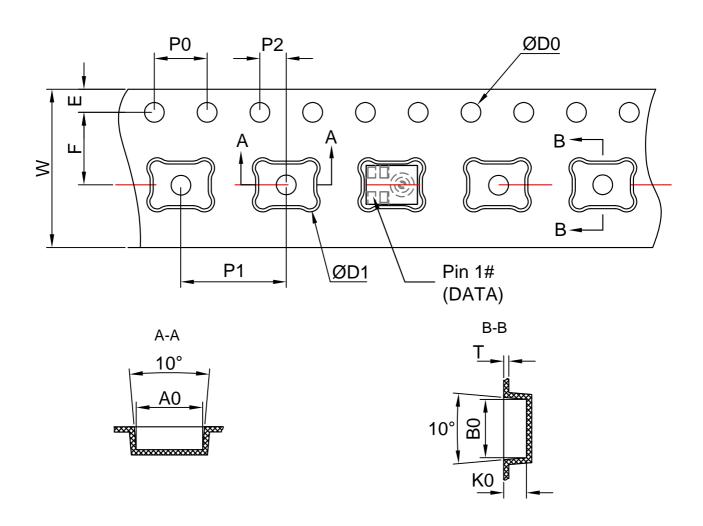
# 7 Reliability Test

7.1 Vibration Test	To be no interference in operation after vibrations, 4 cycles, from 20 to 2000HZ in each direction (X,Y,Z), 48min, user acceleration of 20g, sensitivity should vary within ±3dB from initial sensitivity. (The measurement to be done after 2 hours of conditioning at +15 $^{\circ}$ C $^{\circ}$ +35 $^{\circ}$ C, R.H 25% $^{\circ}$ 75%)
7.2 Drop Test	To be no interference in operation after dropped to 1.0 cm steel plate 12 times from 1.5 meter height in state of JIG,JIG weight of 100 g, sensitivity should vary within ±3dB from initial sensitivity. (The measurement to be done after 2 hours of conditioning at +15 $^{\circ}$ C $^{\circ}$ +35 $^{\circ}$ C, R.H 25% $^{\circ}$ 75%)
7.3 Temperature Test	a) After exposure at +125 °C for 200h, sensitivity should vary within ±3dB from initial sensitivity.  (The measurement to be done after 2h of conditioning at +15 °C ~+35 °C, R.H 25% ~75%)  b) After exposure at -40 °C for 200h, sensitivity should vary within ±3dB from initial sensitivity.  (The measurement to be done after 2 hours of conditioning at +15 °C ~+35 °C, R.H 25% ~75%)
7.4 Humidity Test	After exposure at +85 $^{\circ}$ C and 85% relative humidity for 200 hours, sensitivity should vary within ±3dB from initial sensitivity. (The measurement to be done after 2 hours of conditioning at +15 $^{\circ}$ C $^{\circ}$ +35 $^{\circ}$ C, R.H 25% $^{\circ}$ 75%)
7.5 Mechanical Shock Test	Then subject samples to three one-half sine shock pulses (3000 g for 0.3 milliseconds) in each direction (for six axes in total) along each of the three mutually perpendicular axes for a total of 18 shocks, sensitivity should vary within ±3dB from initial sensitivity. (The measurement to be done after 2 hours of conditioning at +15 $^{\circ}$ C $^{\circ}$ +35 $^{\circ}$ C, R.H 25% $^{\circ}$ 75%)
7.6 Thermal Shock Test	After exposure at -40 $^{\circ}$ C for 30min, at +125 $^{\circ}$ C for 30min (change time 20 seconds) 32 cycles, sensitivity should vary within ±3dB from initial sensitivity. (The measurement to be done after 2 hours of conditioning at +15 $^{\circ}$ C $^{\circ}$ +35 $^{\circ}$ C, R.H 25% $^{\circ}$ 75%)
7.7 Reflow Test	Adopt the reflow curve of item 12.3, after three reflows, sensitivity should vary within $\pm 3dB$ from initial sensitivity. (The measurement to be done after 2 hours of conditioning at +15 $^{\circ}$ C $^{\circ}$ +35 $^{\circ}$ C, R.H 25% $^{\circ}$ 75%)
7.8 ESD Shock Test	Under C=150pF, R=330ohm. Tested to $\pm 2kV$ contact to I/O terminals.10 times. Grounding. Sensitivity should vary within $\pm 3dB$ from initial sensitivity. (The measurement to be done after 2 hours of conditioning at $\pm 15^{\circ}$ C $\rightarrow \pm 35^{\circ}$ C, R.H.25% $\rightarrow \pm 75^{\circ}$ C)



# 8 Package

# **8.1 Tape Specification**



#### The Dimensions as Follows:

ITEM	W	E	F	ØD0	ØD1
DIM(mm)	12.0±0.30	1.75±0.10	5.5±0.05	1.50 <sup>+0.10</sup>	0.50±0.10
ITEM	P0	10P0	P1	A0	B0
DIM(mm)	4.00±0.10	40.00±0.20	8.00±0.10	3.75±0.05	2.85±0.05
ITEM	K0	P2	Т		
DIM(mm)	1.30±0.10	2.00±0.05	0.30±0.05		

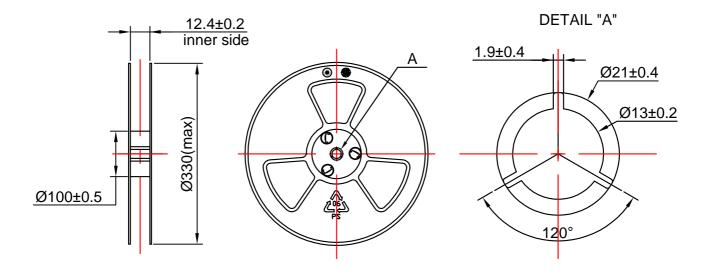
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#### 8.2 Reel Dimension

7" reel for sample stage

13" reel will be provided for the mass production stage

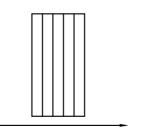
The following is 13" reel dimensions (unit:mm)



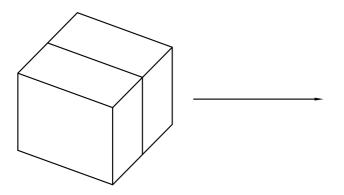
### 8.3 The Content of Box(13" reel)



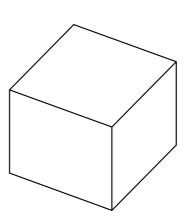
Packing (5,000PCS)



Inner Box(25,000PCS) (340mm×135mm×355mm)



Two Inner Box(50,000PCS)



Outer Box(50,000PCS) (370mm×300mm×390mm)



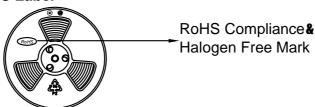
#### 8.4 Packing Explain





The Content Includes: Product type, Lot, Customer P/N; and other essential information such as Quantity, Date etc.

#### 8.4.2 The RoHS Label



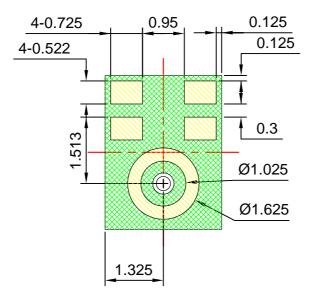
## 9 Storage and Transportation

- 9.1 Keep MEMS MIC in warehouse with less than 75% humidity and without sudden temperature change, acid air, any other harmful air or strong magnetic field. Recommend storage period no more than 1 year and floor life(out of bag) at factory no more than 4 weeks.
- 9.2 The MEMS MIC with normal pack can be transported by ordinary conveyances. Please protect products against moist, shock, sunburn and pressure during transportation.
- 9.3 Storage Temperature Range: -40°C~+70°C
- 9.4 Operating Temperature Range: -40°C ~+100°C

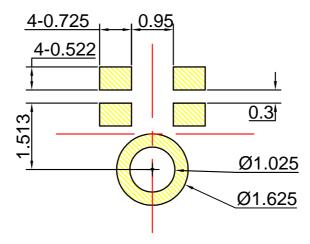


## 10 Land Pattern Recommendation

#### 10.1 The Pattern of MIC Pad(Unit:mm)



## 10.2 Recommended Soldering Surface Land Pattern (Unit:mm)



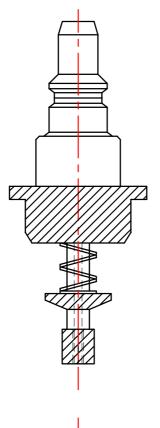


# 11 Soldering Recommendation

#### 11.1 Soldering Machine Condition

Temperature Control	8 zones
Heater Type	Hot Air
Solder Type	Lead-free

#### 11.2 The Drawing and Dimension of Nozzle



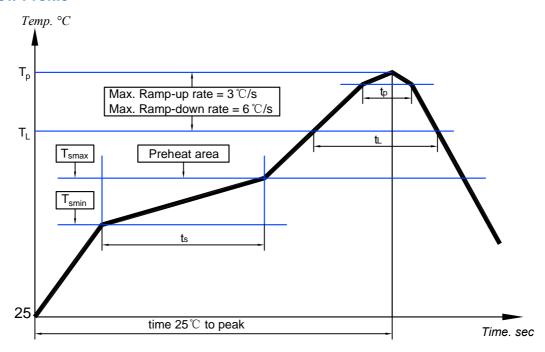
Inside Diameter: 1.0mm;

Please don't vacuum over the acoustic port directly. Please don't blow the acoustic port directly.





#### 11.3 Reflow Profile



## **Key Features of The Profile:**

Average Ramp-up rate(T <sub>smax</sub> to T <sub>p</sub> )	3°C/s max.
Preheat : Temperature $Min(T_{smin})$ Temperature $Max(T_{smax})$ Time $(T_{smin}$ to $T_{smax})(t_s)$	150℃ 200℃ 60~180s
Time maintained above : $Tempreature(T_L) \\ Time(t_L)$	217℃ 60~150s
Peak Temperature(T <sub>p</sub> )	260℃
Time within $5^\circ\!\mathbb{C}$ of actual Peak Temperature( $t_p$ ) :	30~40s
Ramp-down rate(T <sub>p</sub> to T <sub>smax</sub> )	6°C/s max
Time $25^{\circ}\!$	8min max

When MEMS MIC is soldered on PCB, the reflow profile is set according to solder paste and the thickness of PCB etc.



#### 11.4 Rework

- (1)  $250^{\circ}$ C $\sim$ 270 $^{\circ}$ C, maximum 30 sec, Peak temperature 330 $^{\circ}$ C.
- (2) Wind speed: 15L/m.
- (3) It is very important not to put a heatgun over the acoustic port of the microphone.

## 12 Cautions When Using MEMS MIC

#### 12.1 Board Wash Restrictions

It is very important not to wash this silicon microphone, otherwise this could damage the microphone.

#### 12.2 Sound Hole Protection

It is very important not to operate vacuum and air blow into sound hole(without any covering over sound holes), otherwise this could damage the microphone.

And it is necessary to be careful about foreign substances into sound hole inside silicon microphone.

#### 12.3 Wire width Adaption

It is needed to adjust the dumping resistance according to the wire length and wire tod, etc. when using.

It is also necessary to insert dumping resistance in the Data line located adjacent to the microphone according to circumstances.

#### 12.4 Ultrasonic Restrictions

It is very important not to use ultrasonic process. otherwise this could damage the microphone.

## 13 Output Inspection Standard

Output inspection standard is executed according to <<ISO2859-1:1999>>.

# 单击下面可查看定价,库存,交付和生命周期等信息

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